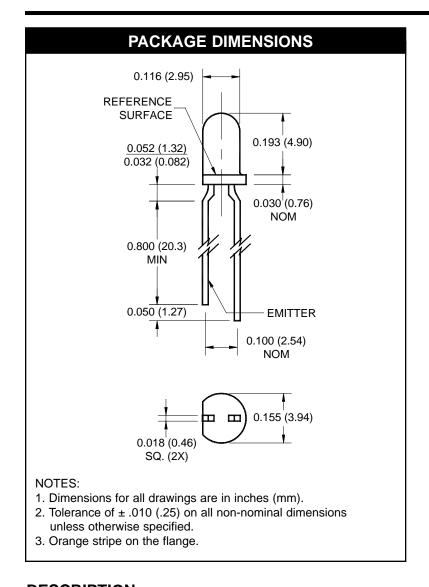
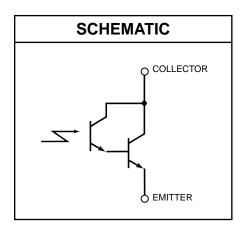
QSC133







DESCRIPTION

The QSC133 is a silicon phototdarlington encapsulated in an infrared transparent, black T-1 package.

FEATURES

- NPN Silicon Photodarlington
- Package Type: T-1 (3mm lens diameter)
- Matched Emitter: QECXXX
- Narrow Reception Angle, 16°
- Daylight Filter
- · Package material and color: black epoxy
- High Sensitivity



QSC133

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)						
Parameter	Symbol	Rating	Unit			
Operating Temperature	T _{OPR}	-40 to +100	°C			
Storage Temperature	T _{STG}	-40 to +100	°C			
Soldering Temperature (Iron)(2,3,4)	T _{SOL-I}	240 for 5 sec	°C			
Soldering Temperature (Flow)(2,3)	T _{SOL-F}	260 for 10 sec	°C			
Collector-Emitter Voltage	V _{CE}	30	V			
Emitter-Collector Voltage	V _{EC}	5	V			
Power Dissipation ⁽¹⁾	P _D	100	mW			

- 1. Derate power dissipation linearly 2.00 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.
- 5. λ = 880 nm, AlGaAs.

ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C)								
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS		
Peak Sensitivity Wavelength		λ_{PS}	_	880	_	nm		
Reception Angle		θ	_	±8	_	Deg.		
Collector-Emitter Dark Current	V _{CE} = 10 V, Ee = 0	I _{CEO}	_	_	100	nA		
Collector-Emitter Breakdown	$I_C = 1 \text{ mA}$	BV _{CEO}	30	_	_	V		
Emitter-Collector Breakdown	I _E = 100 μA	BV _{ECO}	5	_	_	V		
On-State Collector Current ⁽⁵⁾	$Ee = 0.25 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	Ic(on)	8.00	_	_	mA		
Saturation Voltage ⁽⁵⁾	$Ee = 0.25 \text{ mW/cm}^2$, $I_C = 0.4 \text{ mA}$	$V_{CE(sat)}$	_	_	1.0	V		
Rise Time	V EVD 100 O L 0.15 mA	t _r	_	20	_	μs		
Fall Time	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_C = 0.15 \text{ mA}$	t _f	_	50	_			



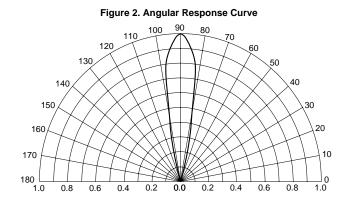
QSC133

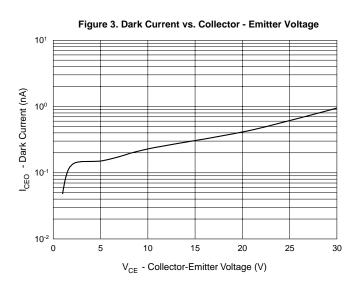
Figure 1. Light Current vs. Radiant Intensity

VCE = 5V
GaAs Light Source

10¹
0.1

E_e - Radiant Intensity (mW/cm²)





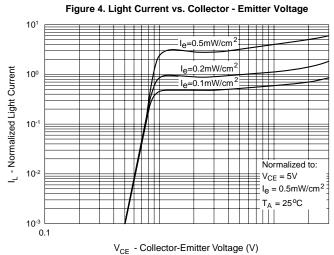


Figure 5. Dark Current vs. Ambient Temperature 10⁵ Normalized to: $V_{CE} = 25V$ 104 T_A= 25 °C - Normalized Dark Current V_{CE}=25V 10³ 10² 10¹ lceo 10⁰ 10⁻¹ 25 100 T_A - Ambient Temperature ($^{\circ}$ C)



QSC133

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body,or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.